

Data Sheet N1154, Rev. A

88CNQ060

RoHS

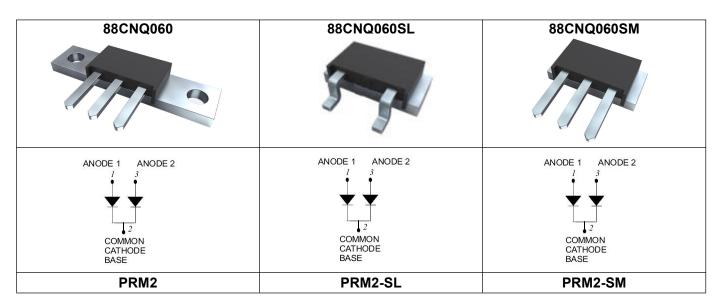
88CNQ060 SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 175℃ T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	60	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _c =95°C, rectangular wave form	40(Per Leg) 80(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	720	А
Non-Repetitive Avalanche Energy(peg leg)	Eas	T _J =25℃,I _{AS} =1A,L=0.57mH	75	mJ
Repetitive Avalanche Current(peg leg)	l _{ar}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5× V_R typical	1	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per leg) *	V _{F1}	@ 40A, Pulse, T」 = 25 °C @ 80A, Pulse, T」 = 25 °C	0.45 0.60	0.58 0.77	V
	V _{F2}	@ 40A, Pulse, T _J = 125 °C @ 80A, Pulse, T _J = 125 °C	0.51 0.54	0.56 0.67	V
Reverse Current (Per leg) *	I _{R1}	$@V_R = rated VR T_J = 25 °C$	0.4	0.64	mA
	I _{R2}	$@V_R = rated VR T_J = 125 °C$	200	240	mA
Junction Capacitance (Per leg)	CT	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2000	5200	pF

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

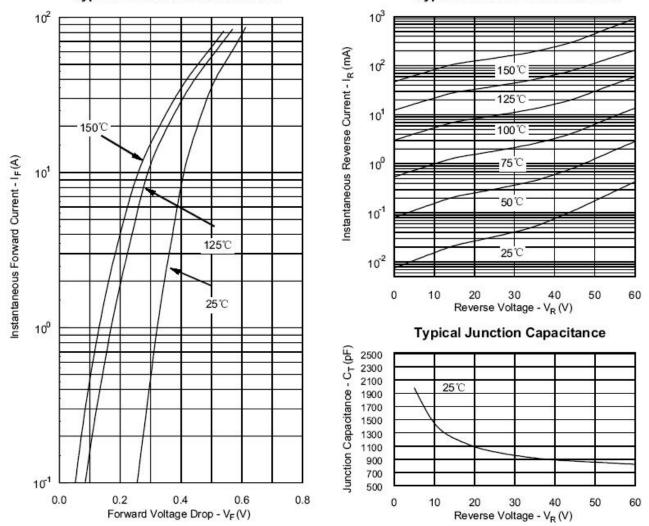
Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +175	°C	
Storage Temperature	T _{stg}	-	-55 to +175	°C	
Typical Thermal Resistance Junction to Case (per leg)	R _{0JC}	DC operation	0.85	°C/W	
Typical Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.42	°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.30	°C/W	
Mounting Torque	ТМ	-	40(min)		
			58(max)	Kg-cm	
Approximate Weight	wt	-	7.8	g	
Case Style	PRM2 PRM2-SL PRM2-SM				

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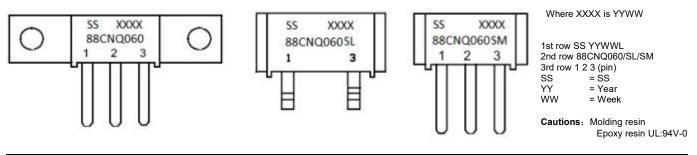
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Ratings and Characteristics Curves



Typical Forward Characteristics

Marking Diagram



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Typical Reverse Characteristics



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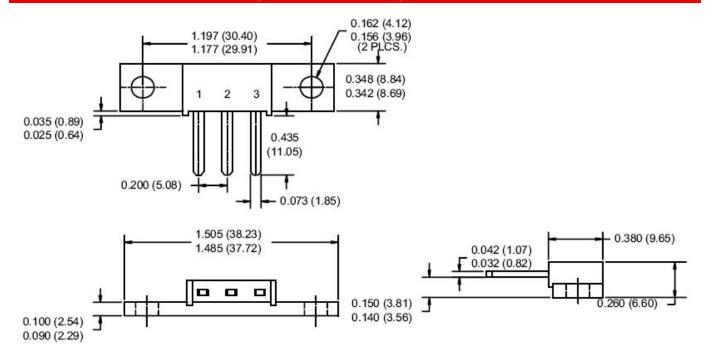
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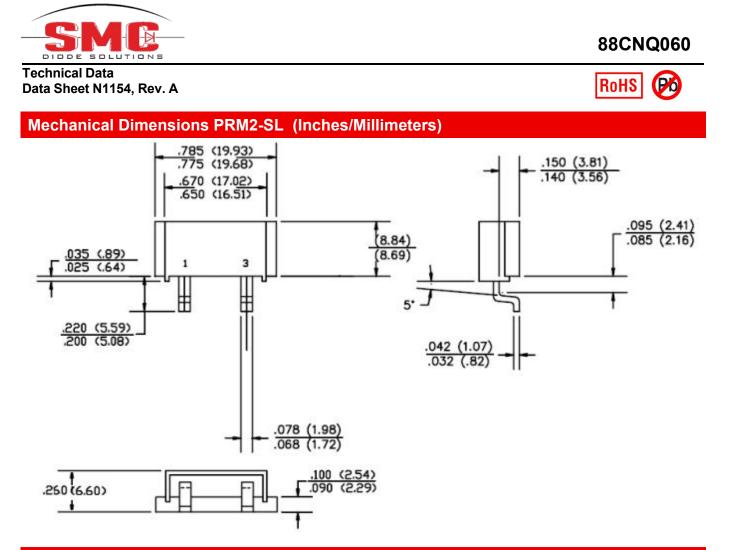
Ordering Information

Device	Package	Terminals finish	Baseplate finish	Shipping
88CNQ060	PRM2	Nickel plated	Nickel plated	48pcs / box
88CNQ060S2	PRM2	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
88CNQ060SL	PRM2-SL	Pure Sn plated	Pure Sn plated	100pcs / box
88CNQ060SM	PRM2-SM	Nickel plated	Nickel plated	48pcs / box
88CNQ060SMS2	PRM2-SM	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

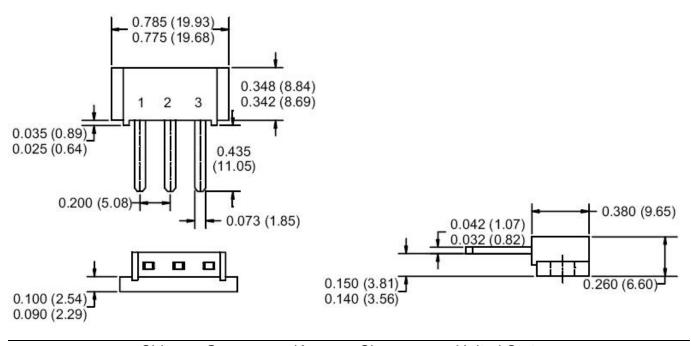
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Mechanical Dimensions PRM2 (Inches/Millimeters)





Mechanical Dimensions PRM2-SM (Inches/Millimeters)



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